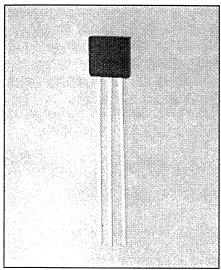


Hallogic[®] Hall Effect Sensors Type OH180U





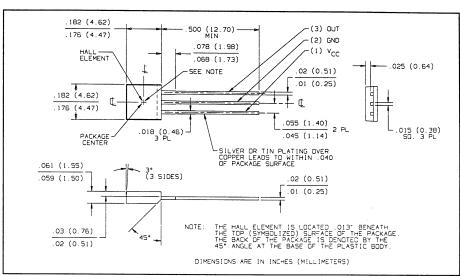
- Operates over a broad range of supply voltages
- Excellent temperature stability to operate in harsh environments
- · Drive capability up to 10 TTL loads
- Hall element, linear amplifier, and Schmitt trigger on a single Hallogic[®] silicon chip

Description

The OH180U contains a monolithic integrated circuit which incorporates a Hall element, a linear amplifier, and Schmitt trigger on a single silicon chip. Included on-chip is a bandgap voltage regulator to allow operation with a wide range of supply voltages. The device features logic level output and provides up to 30 mA of sink current. This allows direct driving of more than 10 TTL loads or any standard logic family using power supplies ranging from 4.5 to 24 volts. Output amplitude is constant at switching frequencies from DC to over 200 kHz.

The OH180U is a high performance device capable of operation from -40° C to +150° C. Stability of the magnetic operate and release points is excellent over this entire temperature range.

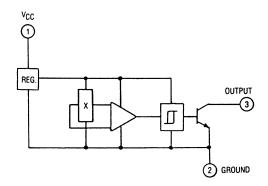
Package size has been kept to minimum, providing an advantage in applications where space is limited.



Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Supply Voltage, V _{CC}
Storage Temperature Range, T _S 65° C to +160° C
Operating Temperature Range, T _A 40° C to +150° C
Lead Soldering Temperature [1/8 inch (3.2 mm) from case for 5 sec. with soldering
iron]
Output ON Current, ISINK
Output OFF Voltage, V _{OUT}
Magnetic Flux Density, B
Note:
(1) Heat sink leads during hand soldering.

Functional Block Diagram



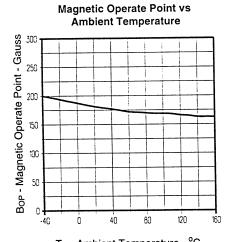
Type OH180U

Electrical Characteristics (V_{CC} = 4.5 V to 24 VDC, T_A = 25° C unless otherwise noted)

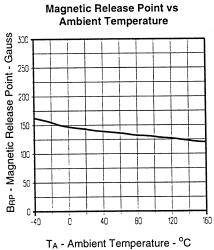
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Вор	Magnetic Operate Point ⁽²⁾	70	180	290	Gauss	
B _{RP}	Magnetic Release Point	0	140	230	Gauss	
Вн	Magnetic Hysteresis	20	40	120	Gauss	
Icc	Supply Current		6	9	mA	V _{CC} = 24 V, Output On
Vol	Output Saturation Voltage		100	300	mV	$V_{CC} = 4.5 \text{ V}, I_{OL} = 30 \text{ mA}$
Іон	Output Leakage Current		0.50	10.0	μΑ	V _{CC} = 24 V, V _{OUT} = 24 V
tr	Output Rise Time		0.30	1.00	μs	$R_L = 820 \Omega$, $C_L = 20 pF$
tf	Output Fall Time		0.30	1.00	μs	

⁽²⁾ South pole facing symbolized surface.

Typical Performance Curves



T_A - Ambient Temperature - °C



T_A - Ambient Temperature - °C

